Type L#	T#	Hits	Search Text	DBs	Time Stamp	Com	Error Definit ion	Err
IS&R L1	$\Gamma$ 1	3	(("6503788") or ("6645799") or ("6727132")).PN.	US-PGPUB; USPAT	2004/12/09 17:06			
BRS L2	L2	$\kappa$	("5683920"   "5780330"   "6300184").PN.	"5780330" US-PGPUB; USPAT; 2004/12/09 .PN. USOCR 17:36	2004/12/09 17:36	,	:	
BRS	L3		("6503788").URPN.	USPAŢ	2004/12/09 17:38			
BRS	7]	4	("20020110969"   "5683920"   "5780330"   "6300184").PN.	969"   US-PGPUB; USPAT; 2004/12/09   "5780330"   USOCR   17:40	2004/12/09 17:40			
BRS	L5	0	("6645799").URPN.	USPAT	2004/12/09 17:41			
BRS	97	5	("20020110969"   "5683920"   "5780330"   "6300184"   "6503788").PN.	969"   "5780330"   US-PGPUB; USPAT; 2004/12/09 USOCR PN.	2004/12/09 17:42			
BRS	L7	0	("6727132").URPN.	USPAT	2004/12/09 17:42			

Type L#	<b>L</b> #	Hits	Search Text	DBs	$Time\ Stamp ments ion Com ion Com ion Com ion Com ion Com ion Com Com Com Com Com Com Com Com Com Com$	Com	Error Definit ion	Err
BRS L8		11534	CMOS or "CMOS" or 11534(complementary adj metal adj oxide adj semiconductor\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2004/12/09			
 BRS	F)	19807	(doped near10  (amorphous or silicon or poly or polysilicon or poly or polycrystalline)) with (p-USOCR; EPO; JPO; boron or (boron adj filuoride or difluoride)) or BF2 or "BF2" or B or "B")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2004/12/09			

Err			
Com Definit ors		•	
Com			
Time Stamp ments	2004/12/09	2004/12/09 19:13	2004/12/09 19:14
DBs	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
Search Text	((dop\$4 or implant\$8 or introduc\$4 or inject\$4) near10 (amorphous or silicon or polysilicon or poly or polycrystalline)) 35941with (p-type or (p adj type) or boron or (boron adj (fluoride or difluoride)) or BF2 or "BF2" or "BF.sub.2" or B or "B")	L11 60392 (metal\$5 or titanium or tungsten) near3 nitride	BRS L12 10884WN? or WN or TiN or TiN? or "TiN" or "WN"
Hits	35941	60392	10884 18
Γ#	L10	L11	L12
Type L#	BRS	BRS	BRS
	10	11	12

	Type L#	T #	Hits	Search Text	DBs	Time Stamp ments	Com	Error Definit ion	Err
13	BRS L13	L13	26421	(anneal\$4 or heat\$4) 26421 hydrogen or N2 or "N2" 7 or "N.sub.2" or H2 or "H2" or "H.sub.2")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2004/12/09			
4	IS&R L14 2321	L14	2321	((438/199) or (438/216) or (438/223) or (438/224) or (438/227) or (438/228) or (438/229) or (438/230) or (438/231) or (438/232) or (438/232) or	US-PGPUB; USPAT; 2004/12/09 USOCR 19:16	2004/12/09 19:16			
15	BRS	L15	11267 09	BRS L15 11267 11 or 12	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2004/12/09 19:20			
16	BRS	L16	49576	BRS L16 4957615 and 13	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2004/12/09 19:21			

Error Err ors				
Com D ments	/	,		
Time Stamp ments	2004/12/09 19:21	2004/12/09	2004/12/09 19:26	2004/12/09
DBs	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT:
Search Text	L17 2186 16 and 10	((dop\$4 or implant\$8 or introduc\$4 or inject\$4) near10 (amorphous or silicon or polysilicon or 38254poly or polycrystalline)) with (n-type or (n adj type) or phosphorous or arsenic or antimony)	L19 1655 17 and 18	19 and 8
Hits	2186	38254	1655	745
Type L#	L17.	L18	L19	L20 745
Туре	BRS	BRS	BRS	BRS
	17	<b>8</b>	19	20

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DBs
Search Text
Type L # Hits
<b>F</b> #
Туре

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	3	(("6503788") or ("6645799") or ("6727132")).PN.	US-PGPUB; USPAT	OR	OFF	2004/12/09 17:06
L2	3	("5683920"   "5780330"   "6300184").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2004/12/09 17:36
L3	3	("6503788") URPN.	USPAT	OR	OFF	2004/12/09 17:38
L4	4	("20020110969"   "5683920"   "5780330"   "6300184").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2004/12/09 17:40
L5	0	("6645799").URPN.	USPAT	OR	OFF	2004/12/09 17:41
L6	5	("20020110969"   "5683920"   "5780330"   "6300184"   "6503788").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2004/12/09 17:42
L7	0	("6727132").URPN.	USPAT	OR	OFF	2004/12/09 17:42
L8	115344	CMOS or "CMOS" or (complementary adj metal adj oxide adj semiconductor\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	OFF	2004/12/09 19:10
L9	19807	(doped near10 (amorphous or silicon or polysilicon or poly or polycrystalline)) with (p-type or (p adj type) or boron or (boron adj (fluoride or difluoride)) or BF2 or "BF2" or "BF.sub.2" or B or "B")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/09 19:12
L10	35941	((dop\$4 or implant\$8 or introduc\$4 or inject\$4) near10 (amorphous or silicon or polysilicon or polycrystalline)) with (p-type or (p adj type) or boron or (boron adj (fluoride or difluoride)) or BF2 or "BF2" or "BF.sub.2" or B or "B")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/09 19:23
L11	60392	(metal\$5 or titanium or tungsten) near3 nitride	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/09 19:13
L12	1088418	WN? or WN or TiN or TiN? or "TiN" or "WN"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/09 19:14

L13	264217	(anneal\$4 or heat\$4) with (nitrogen or hydrogen or N2 or "N2" or "N.sub.2" or H2 or "H2" or "H.sub.2")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/09 19:16
L14	2321	((438/199) or (438/216) or (438/223) or (438/224) or (438/227) or (438/228) or (438/229) or (438/230) or (438/231) or (438/232) or (438/233)).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2004/12/09 19:16
L15	1126709	11 or 12	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/09 19:20
L16	49576	15 and 13	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/09 19:21
L17	2186	16 and 10	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/09 19:21
L18	38254	((dop\$4 or implant\$8 or introduc\$4 or inject\$4) near10 (amorphous or silicon or polysilicon or polysilicon or poly or polycrystalline)) with (n-type or (n adj type) or phosphorus or phosphorous or arsenic or antimony)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/09 19:25
L19	1655	17 and 18	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/09 19:26
L20	745	19 and 8	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/09 19:34

L21	519	20 and (@ad<="20000816" or @rlad<="20000816")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/09 20:23
L22	226		US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ÖR	OFF	2004/12/09 20:23